SCHOTTKY BARRIER MIXER DIODES

LOW BARRIER (N-TYPE)

FREQUENCY BAND	TYPE NUMBER	NF[1] (dB)	Z_{IF}[2] (OHMS)		VSWR	TEST FREQUENCY MHz
		MAX	MIN	MAX	MAX	
S	AML3001	5.5	100	300	1.7	3060
S	AML3002	6.0	100	300	1.8	3060
S	AML3003	6.5	100	300	2.0	3060
X	AML9001	5.5	200	500	1.6	9375
X	AML9002	6.0	200	500	1.6	9375
X	AML9003	6.5	200	500	1.6	9375
X	AML9004	7.0	200	500	1.6	9375
K_μ	AML1601	6.0	200	500	1.6	16000
K_μ	AML1602	6.5	200	500	1.6	16000
K_μ	AML1603	7.0	200	500	1.6	16000
K_μ	AML1604	7.5	200	500	1.6	16000
K_a	AML3501	7.0	300	700	–	34865
K_a	AML3502	7.5	300	700	–	34865
K_a	AML3503	8.0	300	700	–	34865
K_a	AML3504	9.0	300	700	–	34865
K_a	AML3505	10.0	300	700	–	34865

MEDIUM BARRIER (N-TYPE)

FREQUENCY BAND	TYPE NUMBER	NF[1] (dB)	Z_{IF}[2] (OHMS)		VSWR	TEST FREQUENCY MHz
		MAX	MIN	MAX	MAX	
S	AMM3001	5.5	150	400	1.7	3060
S	AMM3002	6.0	150	400	1.8	3060
S	AMM3003	6.5	150	400	2.0	3060
S	AMM3004	7.0	150	400	2.0	3060
X	AMM9001	6.0	200	450	1.6	9375
X	AMM9002	6.5	200	450	1.6	9375
X	AMM9003	7.0	200	450	1.6	9375
X	AMM9004	7.5	200	450	1.8	9375
X	AMM9005	8.0	200	450	2.0	9375
K_μ	AMM1601	6.5	250	600	1.6	16000
K_μ	AMM1602	7.0	250	600	1.8	16000
K_μ	AMM1603	7.5	250	600	2.0	16000

HIGH BARRIER (N-TYPE)

FREQUENCY BAND	TYPE NUMBER	NF[1] (dB)	Z_{IF}[2] (OHMS)		VSWR	TEST FREQUENCY MHz
		MAX	MIN	MAX	MAX	
S	AMH3001	5.0	250	450	1.6	3060
S	AMH3002	5.5	250	450	1.6	3060
S	AMH3003	6.0	250	450	1.8	3060
S	AMH3004	6.5	250	450	2.0	3060
X	AMH9001	6.0	250	450	1.6	9375
X	AMH9002	6.5	250	450	1.6	9375
X	AMH9003	7.0	250	450	1.8	9375
K_μ	AMH1601	6.5	250	600	1.6	16000
K_μ	AMH1602	7.0	250	600	1.8	16000

LOW BARRIER (P-TYPE)

FREQUENCY BAND	TYPE NUMBER	NF[1] (dB)	Z_{IF}[2] (OHMS)		VSWR	TEST FREQUENCY MHz
		MAX	MIN	MAX	MAX	
S	AMP3001	5.5	100	250	1.6	3060
S	AMP3002	6.0	100	250	1.8	3060
S	AMP3003	6.5	100	250	2.0	3060
X	AMP9001	6.0	100	250	1.6	9375
X	AMP9002	6.5	100	250	1.6	9375
X	AMP9003	7.0	100	250	1.8	9375
K_μ	AMP1601	6.5	150	500	1.6	16000
K_μ	AMP1602	7.0	150	500	1.8	16000

NOTES:

1. NF_{IF} = 1.5 dB; I_F = 30 MHz; R_L = 100 ohms; L.O. = 1 MW (for low and medium barrier types); L.O. = 2.0 MW (for high barrier types); K_a-Band NF is calculated.
2. IF impedance is measured by modulating the specified test frequency with a 1000 Hz signal, R_L = 22 ohms, at the specified incident power level.
3. These diodes are available as matched pairs and are supplied in either forward pairs (M) or forward/reverse pairs (MR). The matching criteria is: $\triangle L_c$ = 0.3 dB max
   $\triangle Z_{IF}$ = 2.5 ohms, max
4. When ordering add package style as a suffix to basic type number to denote desired package style; i.e. AML9002-44 is a 6.0 dB X-Band Low Barrier Mixer Diode in the -44 style package.
5. All of the Schottky Barrier Mixer Diodes are available in chip form.

SCHOTTKY BARRIER DETECTOR DIODES

LOW BARRIER (N-TYPE)

FREQUENCY BAND	TYPE NUMBER	TSS[1] (dBm)	Z_V[2] (KOHMS)		TEST FREQUENCY MHz
		MIN	MIN	MAX	
S	ADN3001	-48	1	2	3060
S	ADN3002	-50	1	2	3060
S	ADN3003	-55	1	2	3060
X	ADN9001	-50	1	2	10000
X	ADN9002	-52	1	2	10000
X	ADN9003	-55	1	2	10000
K_μ	ADN1601	-48	1	2	16000
K_μ	ADN1602	-50	1	2	16000
K_μ	ADN1603	-52	1	2	16000

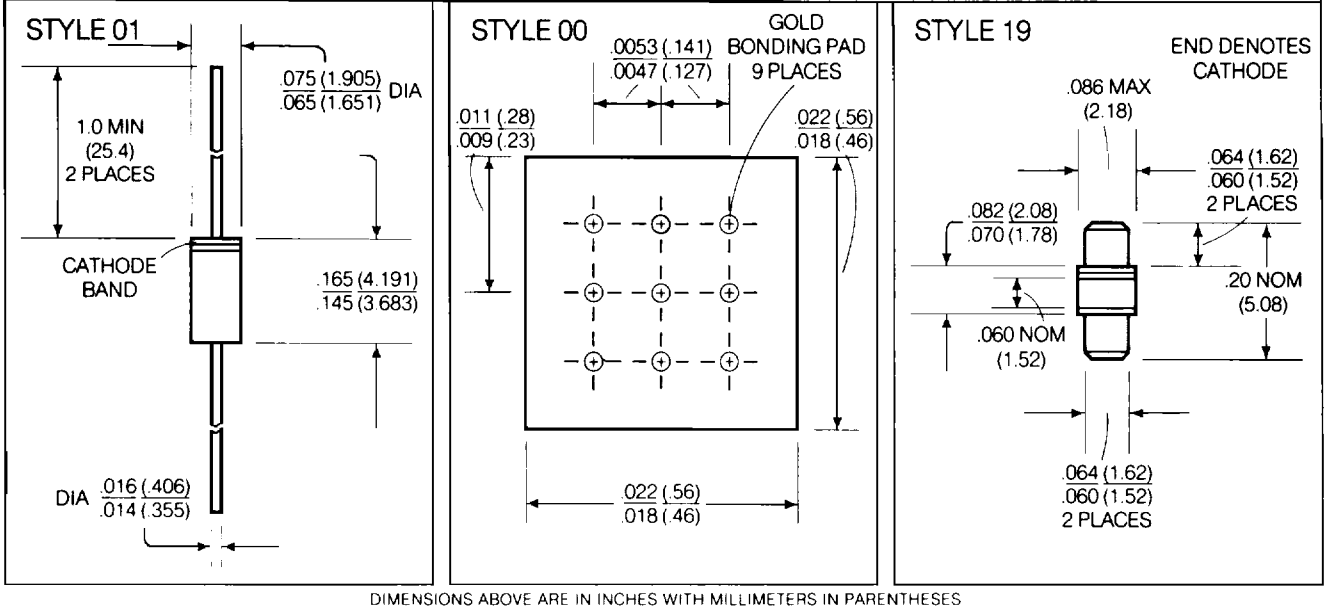
LOW BARRIER (P-TYPE)

FREQUENCY BAND	TYPE NUMBER	TSS[1] (dBm)	Z_V[2] (KOHMS)		TEST FREQUENCY MHz
		MIN	MIN	MAX	
X	ADP9001	-50	1.2	1.8	10000
X	ADP9002	-52	1.2	1.8	10000
X	ADP9003	-55	1.2	1.8	10000
K_μ	ADP1601	-48	1.2	1.8	16000
K_μ	ADP1602	-50	1.2	1.8	16000
K_μ	ADP1603	-52	1.2	1.8	16000
K_a	ADP3601	-47	1.0	2.0	36000
K_a	ADP3602	-49	1.0	2.0	36000

NOTES:

1. **DC Bias is +20μA, Video Bandwidth=2 MHz.**
2. **DC Bias is +20μA, P(incident)=−30 dBm.**
3. **All of the Schottky Barrier Mixer Diodes are available in chip form.**
4. **When ordering add package style as a suffix to basic type number to denote desired package style; i.e. ADN3003-19 is a −55 dBm Low Barrier (N-Type); 5-Band detector diode in the −19 style package.**

PACKAGE STYLES

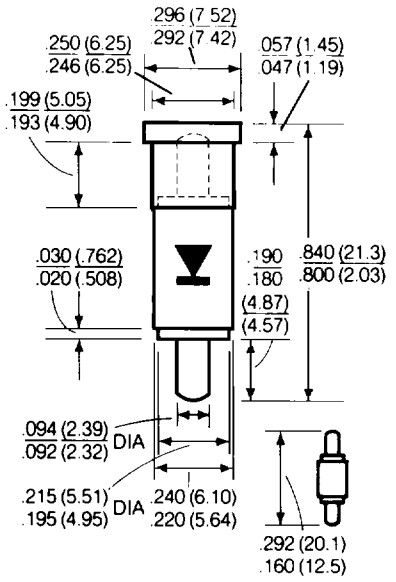


DIMENSIONS ABOVE ARE IN INCHES WITH MILLIMETERS IN PARENTHESES

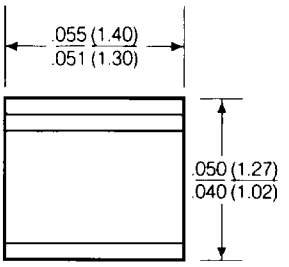
SCHOTTKY BARRIER MIXER DIODES

PACKAGE STYLES

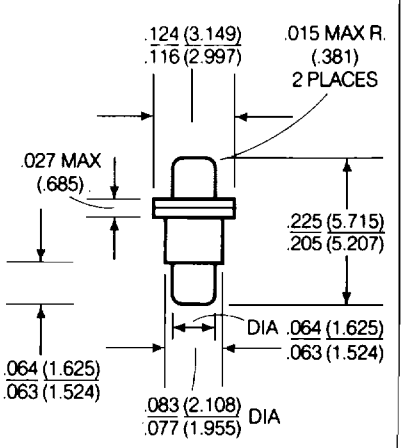
STYLE 23



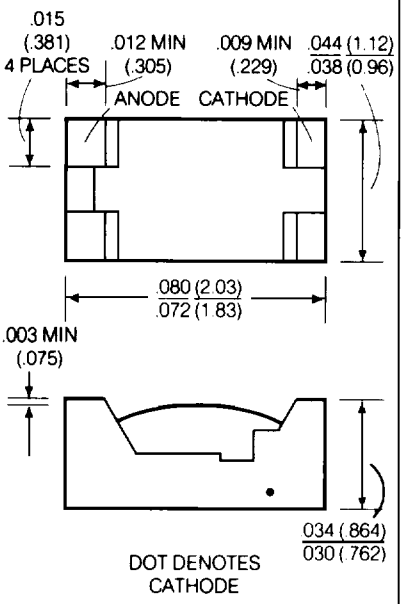
STYLE 44



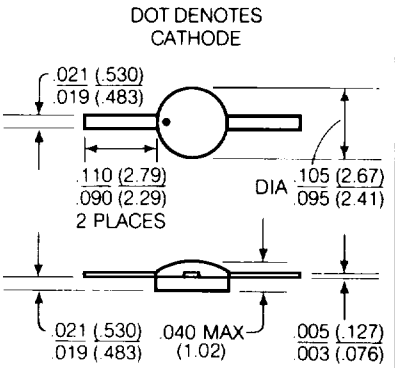
STYLE 51



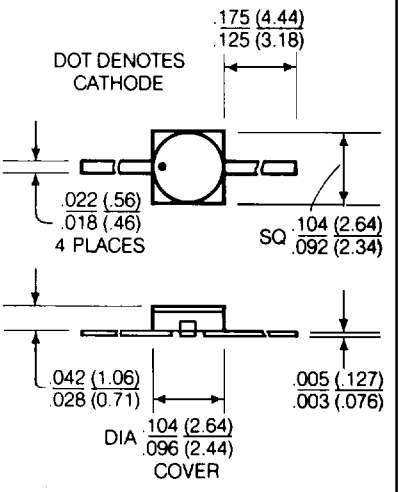
STYLE 91



STYLE 800



STYLE 860



DIMENSIONS ABOVE ARE IN INCHES WITH MILLIMETERS IN PARENTHESES

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